DESCRIPTION

The BAS16BS is available in SOD-882 package.

FEATURE

- Small plastic SMD package.
- Continuous reverse voltage: max. 75 V.
- High-speed switching in hybrid thick and thin-film circuits

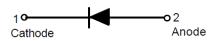
ORDERING INFORMATION

Package Type	Part Number		
SOD-882	BAS16BS		
Note	SPQ: 5,000pcs/Reel		
AiT provides all RoHS Compliant Products			

PIN DESCRIPTION



SOD-882



PIN#	DESCRIPTION		
1	Cathode		
2	Anode		

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^{\circ}C$

V _R , Continuous Reverse Voltage		+75V
I _F , Peak Forward Current		200mA
I _{FSM} , Peak Forward Surge Current		500mA
P _D , Total Device Dissipation FR– 5 Board ⁽¹⁾	T _A = 25°C	200mW
	Derate Above 25°C	1.57mW/°C
R _{0JA} , Thermal Resistance from Junction to Ambient		635°C/W
T _J , Junction and Storage Temperature		-55°C~+150°C
T _{STG} , Junction and Storage Temperature		-55°C~+150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

(1) FR-4 Minimum Pad

ELECTRICAL CHARACTERISTICS

 $T_A = 25$ °C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Reverse Voltage Leakage Current	I _R	V _R =75V	-	-	1	uA
		V _R =75V, T _J = 150°C	-	-	50	
		V _R =25V, T _J = 150°C	-	-	30	
Reverse Breakdown Voltage	V_{BR}	I _{BR} = 100 μA	75	-	-	V
Forward Voltage	V _F	I _F =1mA	-	-	715	mV
		I _F =10mA	-	-	855	
		I _F =50mA	-	-	1000	
		I _F =150mA	-	-	1250	
Diode Capacitance	Cd	f=1MHz, V _R =0	-	-	2	pF
Reverse Recovery Time	Trr	$I_F = I_R = 10 \text{mA}, R_L = 50 \Omega$	-	-	4	nS
Forward Recovery Voltage	V_{FR}	$I_F = 10 \text{mA}, t_r = 20 \text{ns}$	-	-	1.75	V
Stored Charge	Qs	$I_F = 10 \text{mA}, V_R = 5.0 \text{ V},$ $R_L = 500 \Omega$	-	-	45	рС

TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. I_F vs. V_F

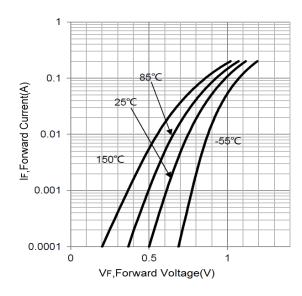


Fig 2. I_R vs. V_R

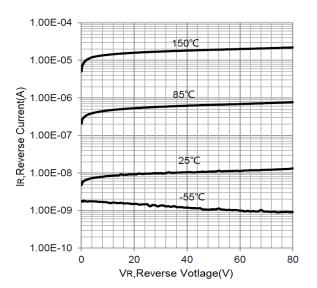
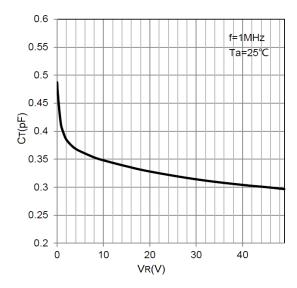
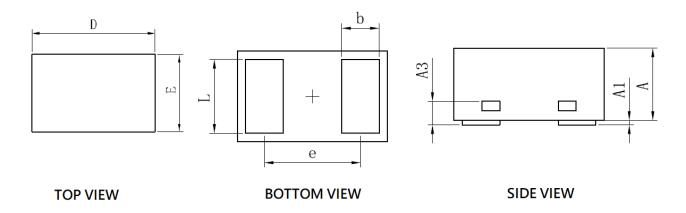


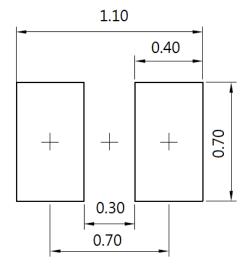
Fig 3. C_T vs. V_R



PACKAGE INFORMATION

Dimension in SOD-882 Package (Unit: mm)





SYMBOL	MIN	MAX	
Α	0.430	0.530	
A1	0.000	0.050	
A3	0.127 REF		
b	0.200	0.300	
D	0.950	1.050	
Е	0.550	0.650	
е	-	-	
L	0.440	0.540	

SOLDERING FOOTPRINT

BAS16BS

SWITCHING DIODE 500mA 75V SWITCHING DIODE

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